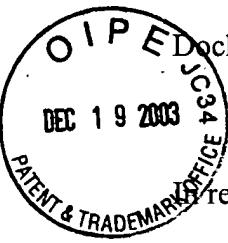


Image



Docket No.: 60188-407

PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Re Application of : Customer Number: 20277
ISHIBASHI, AKIHIKO, et al. : Confirmation Number: 6705
Serial No.: 09/692,211 : Group Art Unit: 2812
Filed: October 20, 2000 : Examiner: Savitri MULPURI
For: METHOD OF FABRICATING NITRIDE SEMICONDUCTOR DEVICE

RESPONSE TO RESTRICTION REQUIREMENT

Mail Stop Restriction Requirement
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Sir:

Noting the Office Action of November 19, 2003 wherein restriction has been required, Applicant(s) hereby elect Species A, for growing plural seed crystals first and followed by growing first nitride layer and second nitride layers at different pressures and different temperatures for prosecution in the above-identified application, and listing of all claims readable thereon are claims 4-8.

While making the foregoing election as required, Applicants respectfully submit that the species should more properly be grouped as claims 8, 10 and 11, and claims 13 and 4-7, as claims 10 and 11 are dependent on claim 8, and claims 4-7 are dependent on claim 13. In any event, Applicants desire the species, as determined by the Examiner, which contains claim 8 to be examined in the pending application.

To the extent necessary, a petition for an extension of time under 37 C.F.R. 1.136 is hereby made. Please charge any shortage in fees due in connection with the filing of this paper, including extension of time fees, to Deposit Account 500417 and please credit any excess fees to such deposit account.

Respectfully submitted,

MCDERMOTT, WILL & EMERY


Michael E. Hogarty
Registration No. 36,139

600 13th Street, N.W.
Washington, DC 20005-3096
(202) 756-8000 MEF:men
Facsimile: (202) 756-8087
Date: December 19, 2003